NSN 5961-01-050-7048

Demilitarization:

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-050-7048 **Inclosure Material:** Metal **Overall Length:** 1.253 inches **End Application:** Mradar set, firefinder (an/tpq-36), generator set, tact quiet, 10kw, 400hz, mep-813a, generator set, 10kw, 60 hz, skid-mounted (2id) (mep-0003a), radar system an/vpq-1, shipboard material handling equipment (mhe). **Mounting Facility Quantity:** 1 **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 480.0 nonrepetitive peak reverse voltage and 400.0 forward gate to source breakdown voltage **Current Rating Per Characteristic:** 12.00 amperes forward current, average absolute and 240.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Weapon system essential **Test Data Document:** 30554-5273 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**